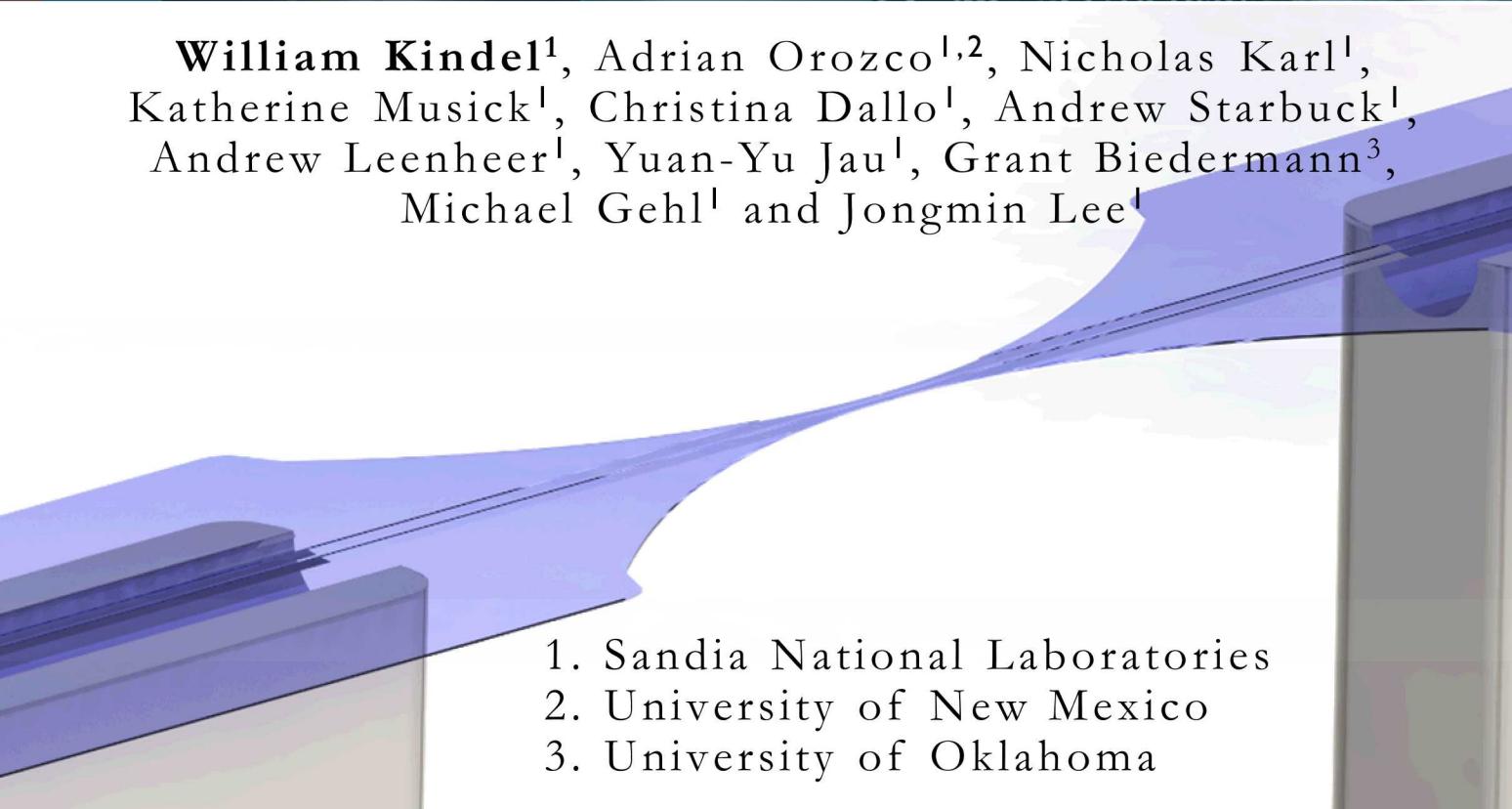
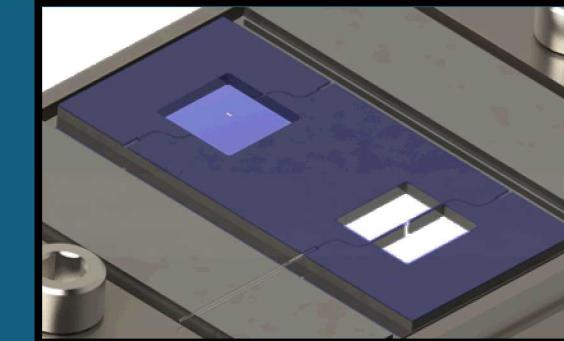


Integrated atomic waveguides for atom interferometry (AI)

William Kindel¹, Adrian Orozco^{1,2}, Nicholas Karl¹,
Katherine Musick¹, Christina Dallo¹, Andrew Starbuck¹,
Andrew Leenheer¹, Yuan-Yu Jau¹, Grant Biedermann³,
Michael Gehl¹ and Jongmin Lee¹

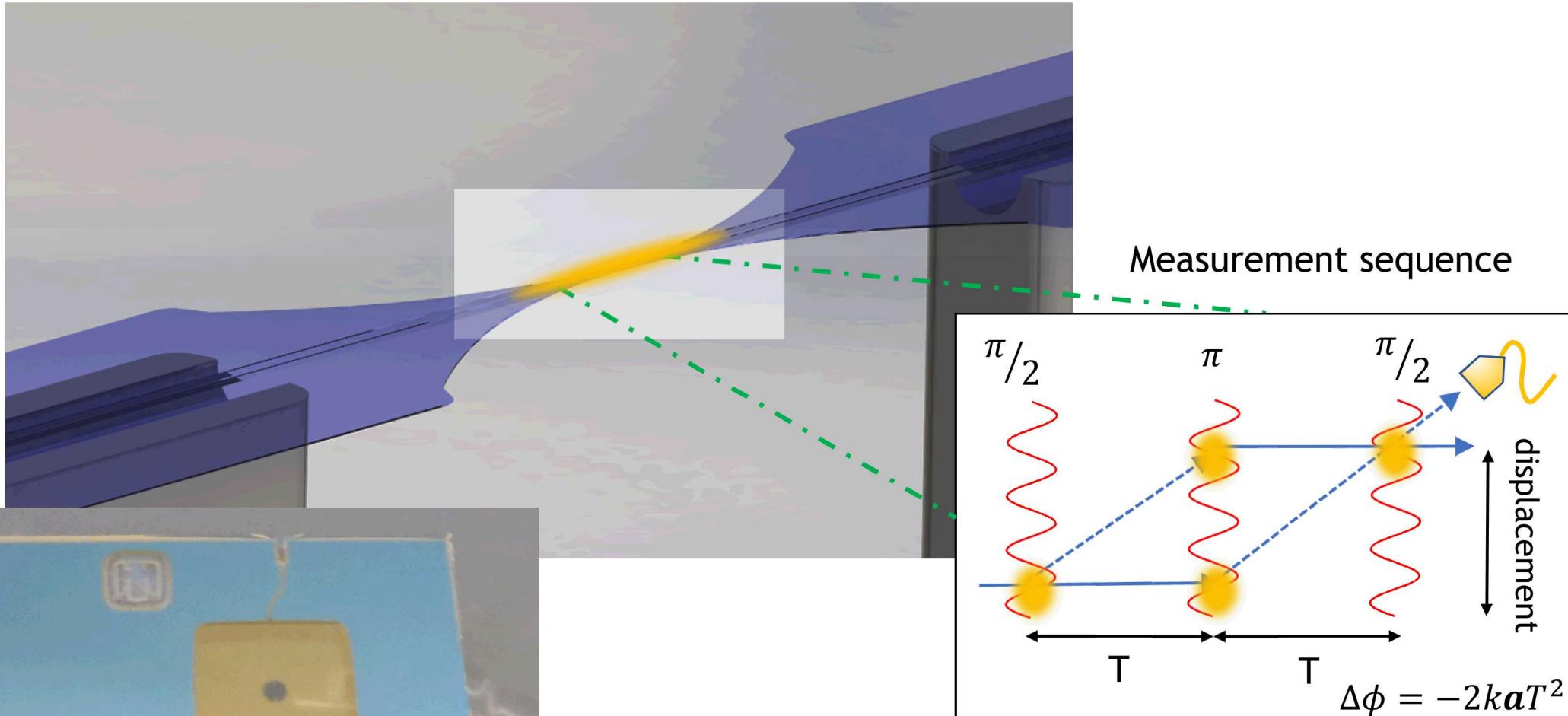


1. Sandia National Laboratories
2. University of New Mexico
3. University of Oklahoma



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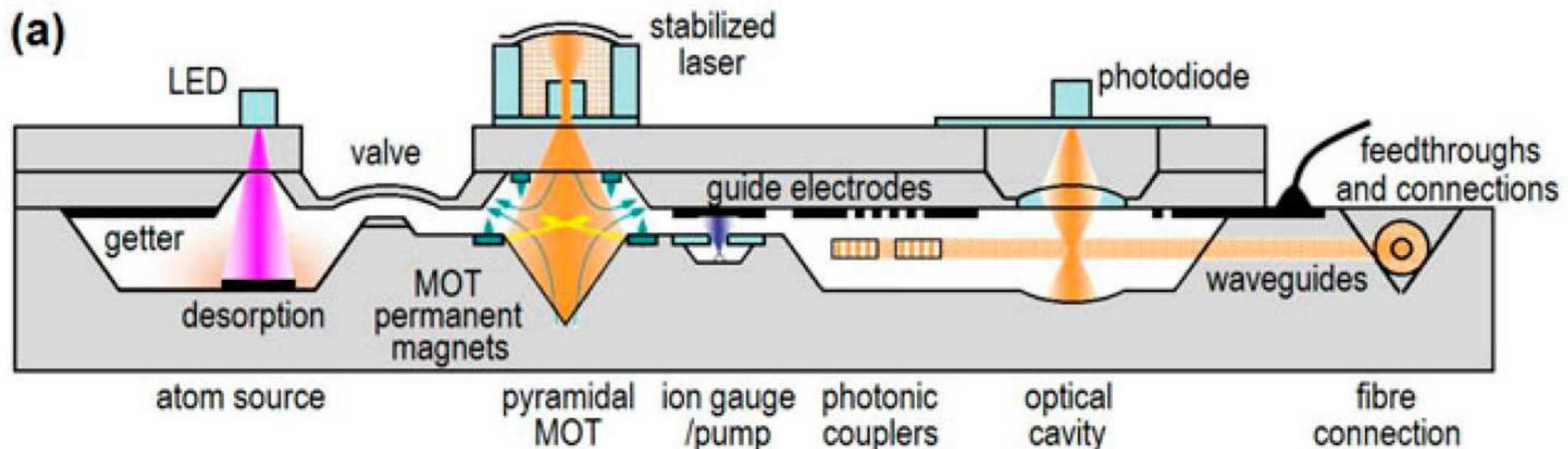
We are making integrated photonic waveguides for atom interferometry



focused on
making the photonic device and
overcoming heat dissipation

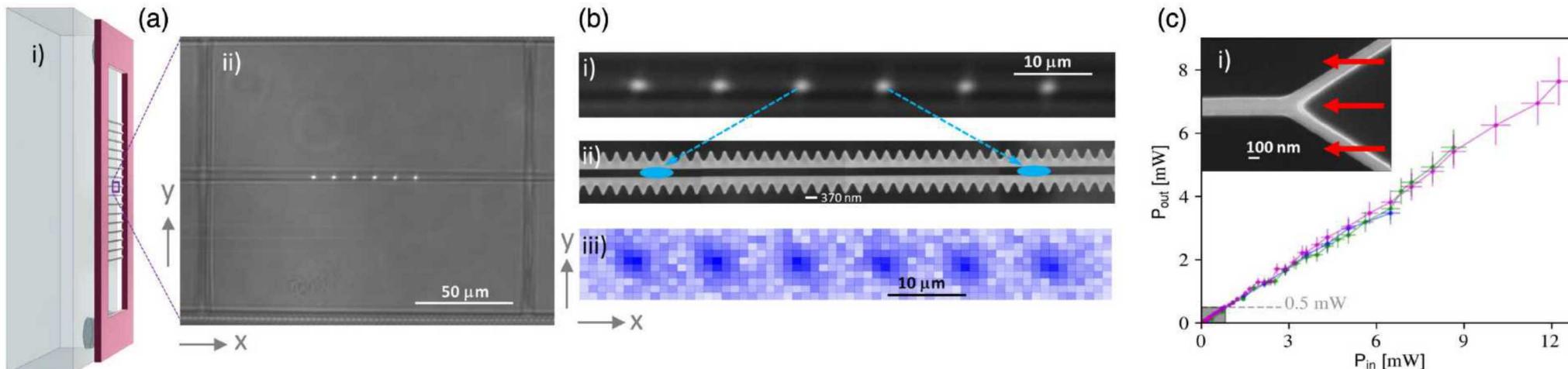
Neutral-atom photonic devices bring fieldable technology and new physics

Concept:
fully integrated atomic devices



Photonic device for
cold atom experiments

Fifteen years of cold matter on the atom chip: promise, realizations, and prospects, M. Keil et al., JOURNAL OF MODERN OPTICS VOL. 63, NO. 18, 1840–1885 (2016)



Advanced apparatus for the integration of nanophotonics and cold atoms,
J. B. Beguin, et al, Optica Vol 7, No 1, 1 (2020)

Guided atom interferometry on chip would bring new capabilities

- 1-D atoms guide ensures atoms pass through each other
- Compact and potentially integrable was photonics and electrical systems
- Parallel systems on same chip
- Strong light-atom interactions
- Low power Raman beams

waveguide mode

1 um scale

~ 1 um² area

free space mode

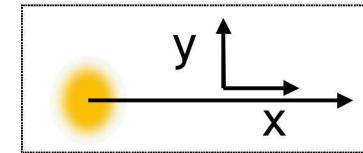
3 mm waist

~ 10⁷ um² area

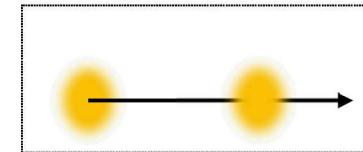
Waveguide needs 10⁷ less power for same intensity!

Sequence with deleterious rotation.
Off axis motion reduces signal.

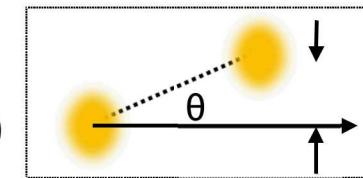
$\pi/2$ pulse



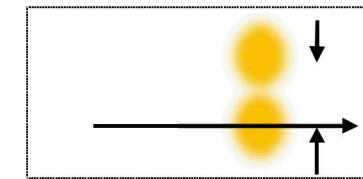
wait T



lab frame
rotates by θ



π pulse and
wait T



no signal!

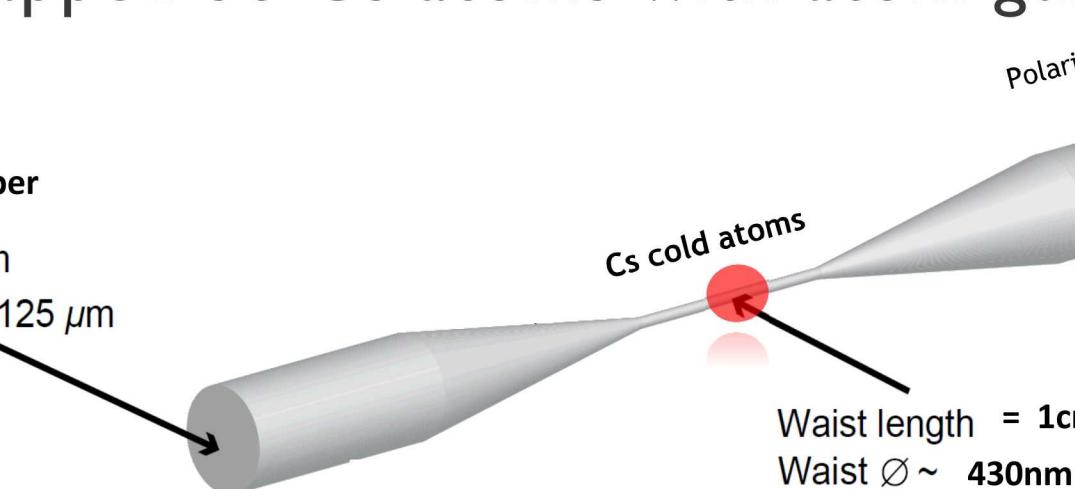
Trapped 38 Cs atoms with atom guide



Commercial fiber

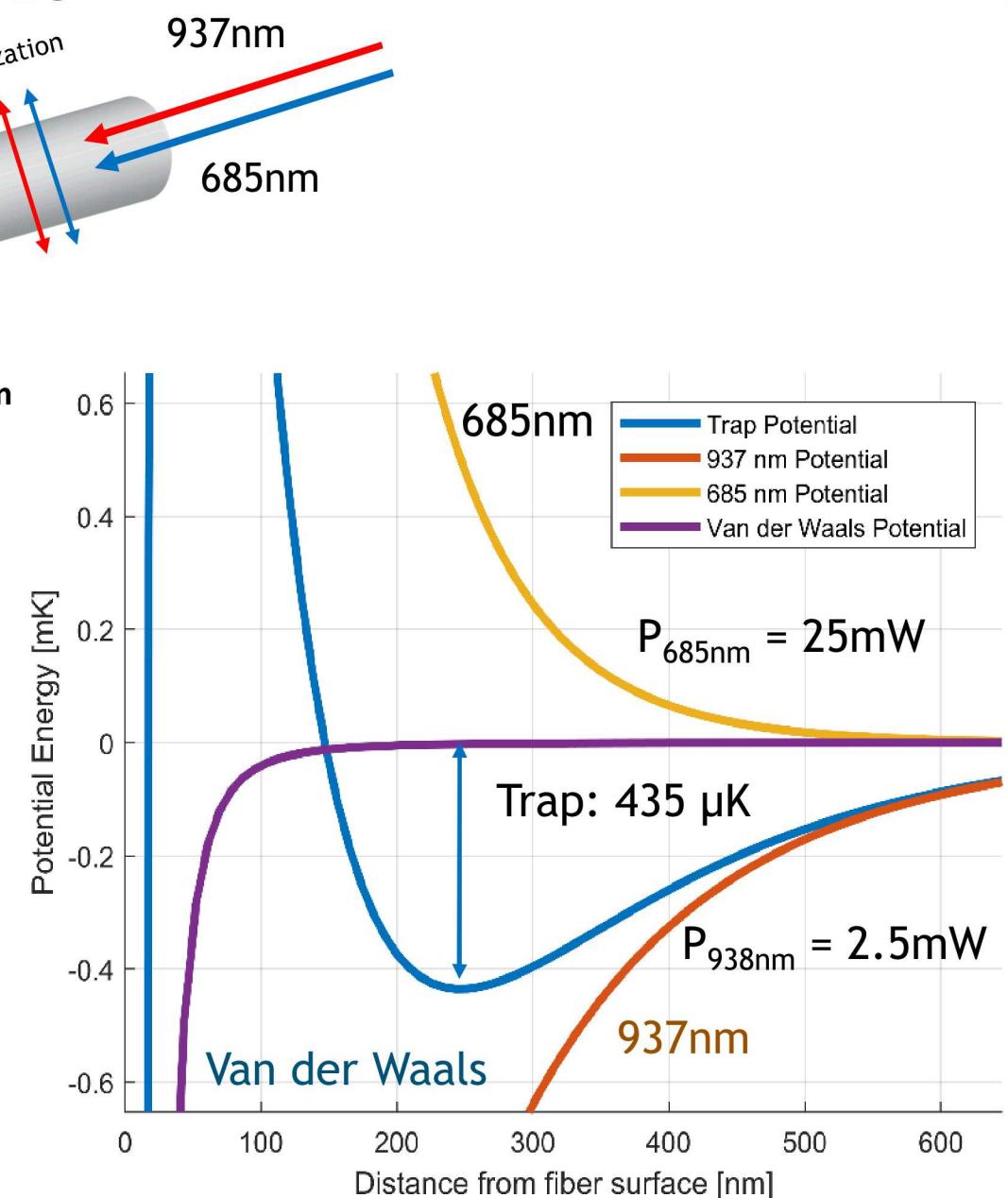
Core $\varnothing \sim 5 \mu\text{m}$

Cladding $\varnothing \sim 125 \mu\text{m}$



(See S02.9 Friday 9:36 am for more details)

- Two-color evanescent fields provide repulsive/attractive forces to trap atoms.
- 1-D dipole trap configuration with Cs magic-wavelengths
- Trap depth = $435 \mu\text{K}$
- Trapped 38 Cs Atoms



6 Steps to making AI photonic platform

Waveguide overlaps with MOT

Waveguide for two color atoms trap



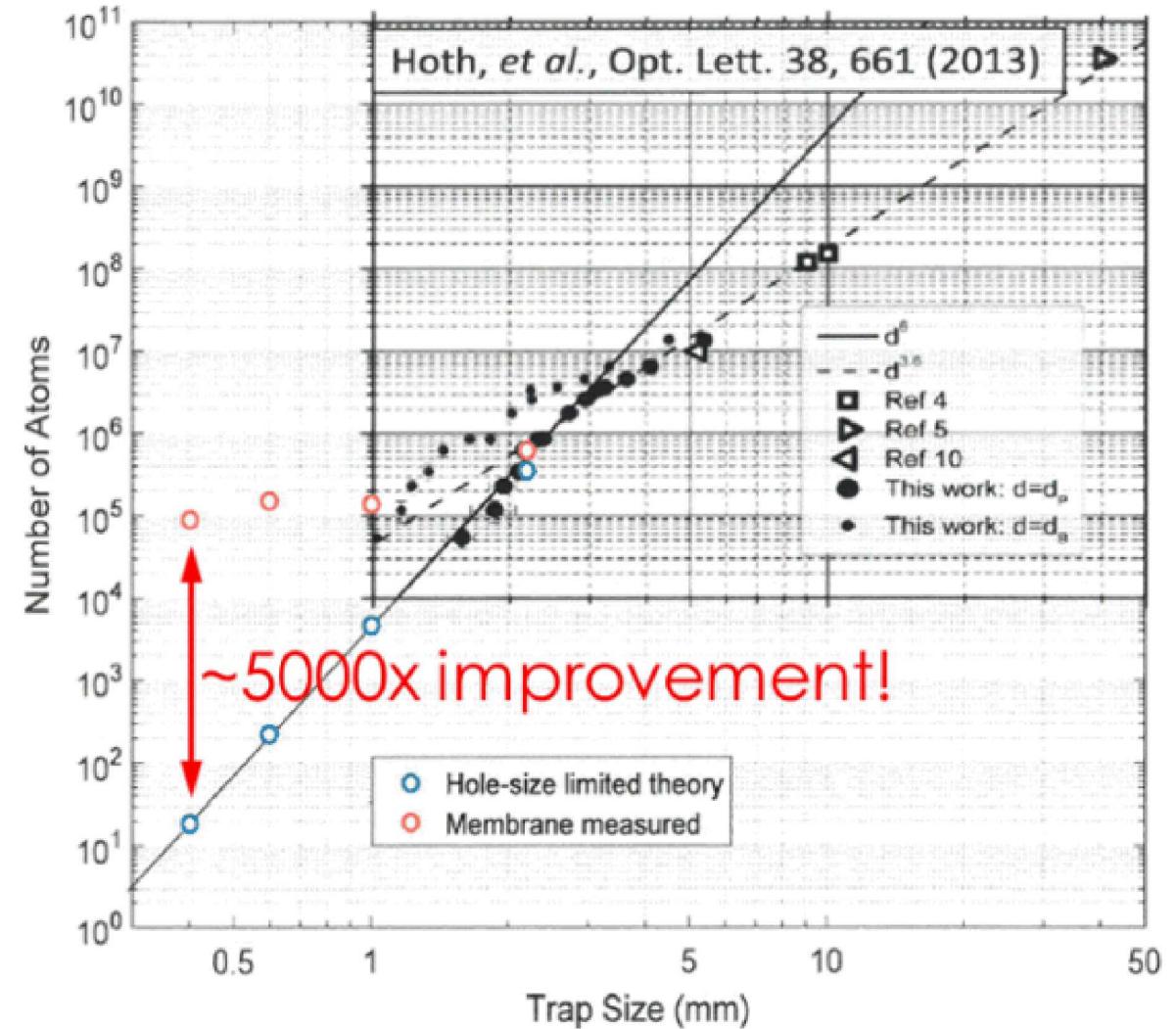
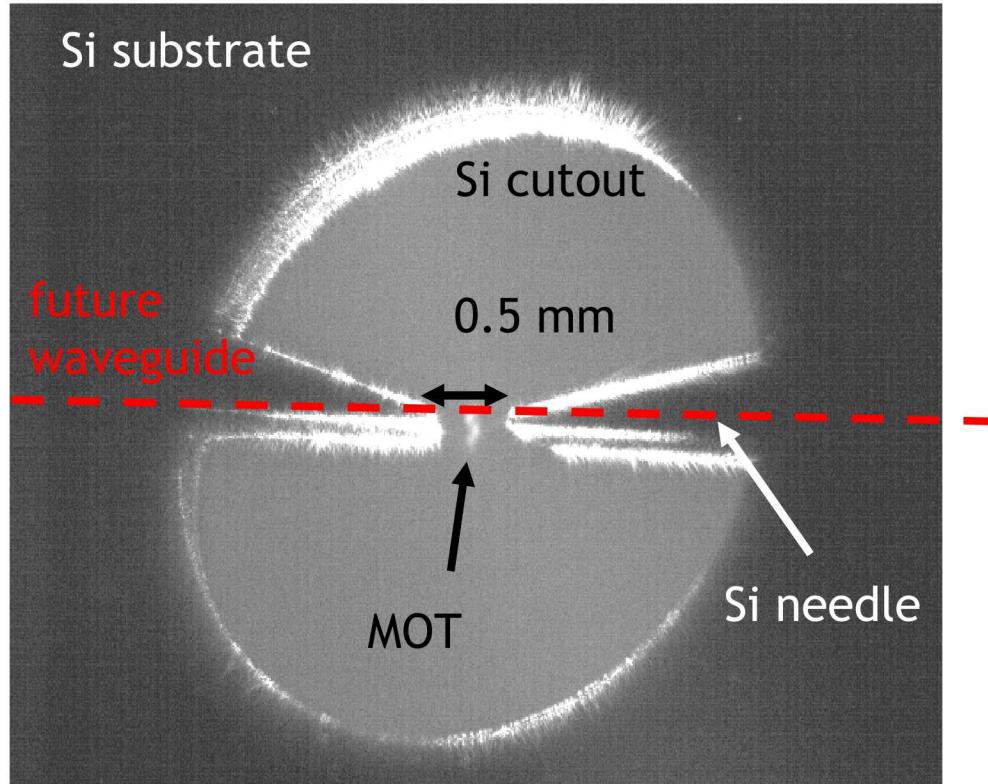
Atoms trapped on waveguide for AI

Waveguide power handling for deep trap

Use nanofiber as guide

435 μK deep trap for order 50 Cs atoms

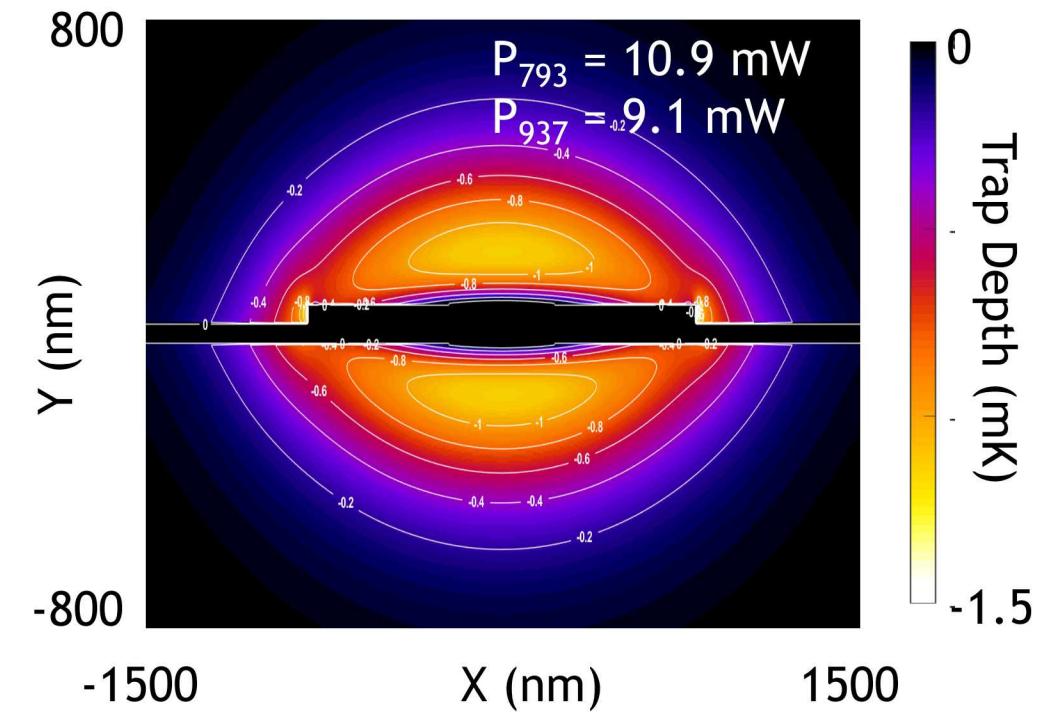
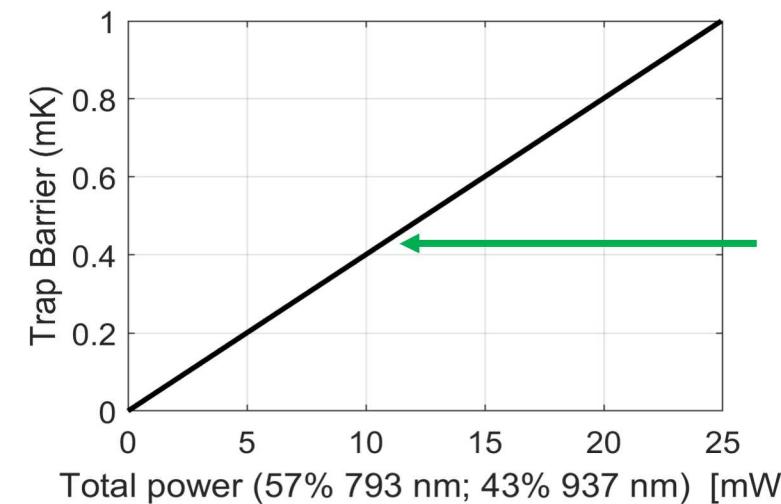
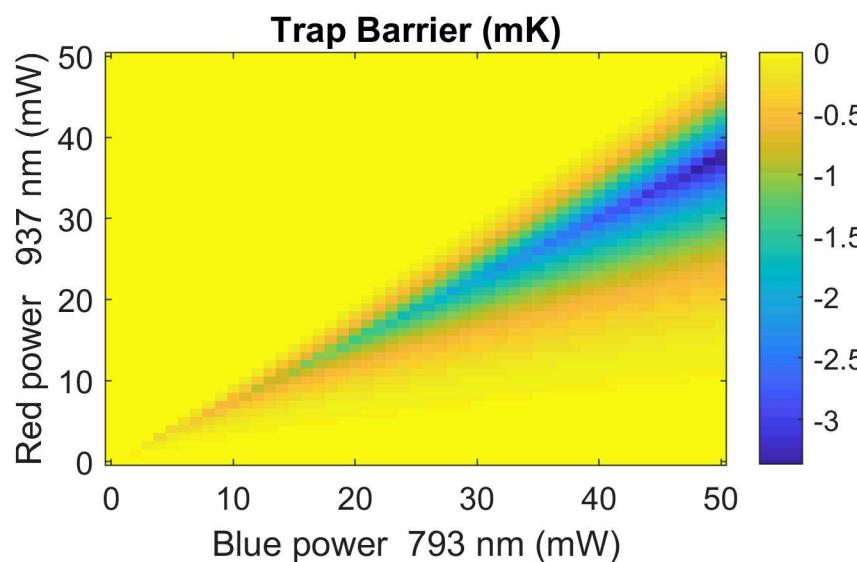
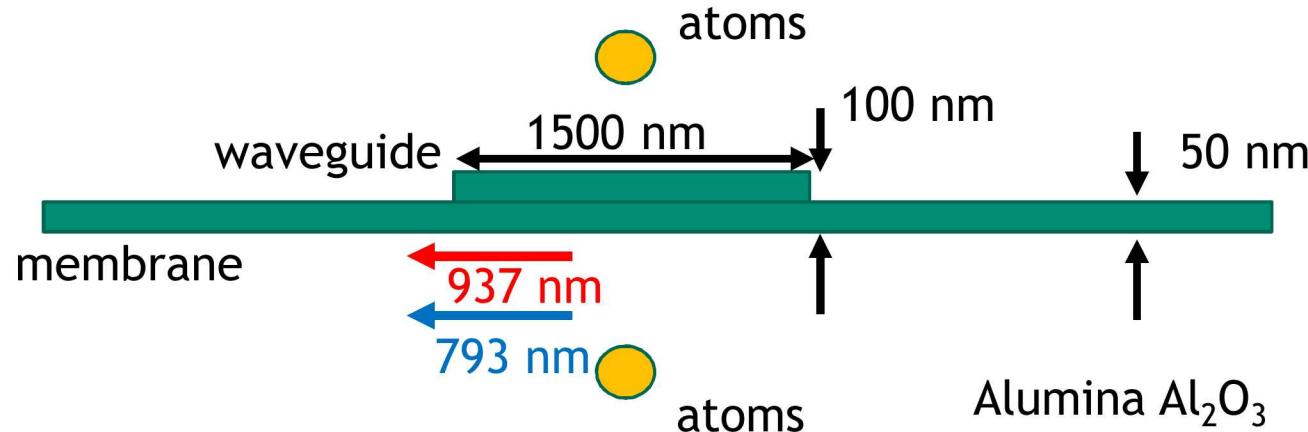
We have previously demonstrated from MOT on chip cut out



0.5 mm diameter membrane cutout
 $\rightarrow N \sim 10^5$ atoms in MOT

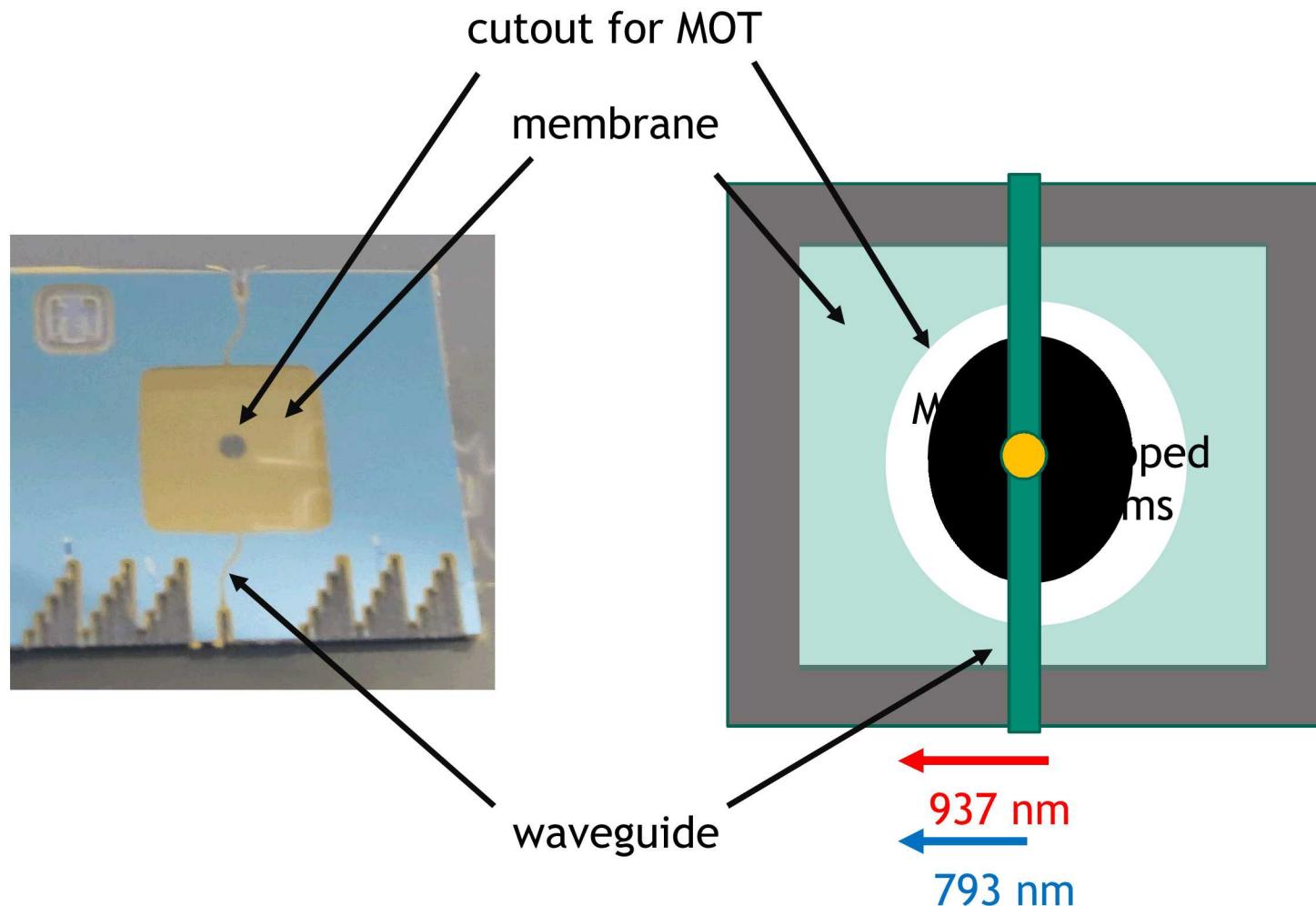
Designing the photonic waveguide form the atom trap

cross section:



11 mW for
0.435 mK trap
(match nanofiber)

9 We fabricate a photonic waveguide chip for atom trapping



Experimental sequence

Turn on 793nm & 937nm trap

Generate MOT around waveguide

Sub-doppler cool

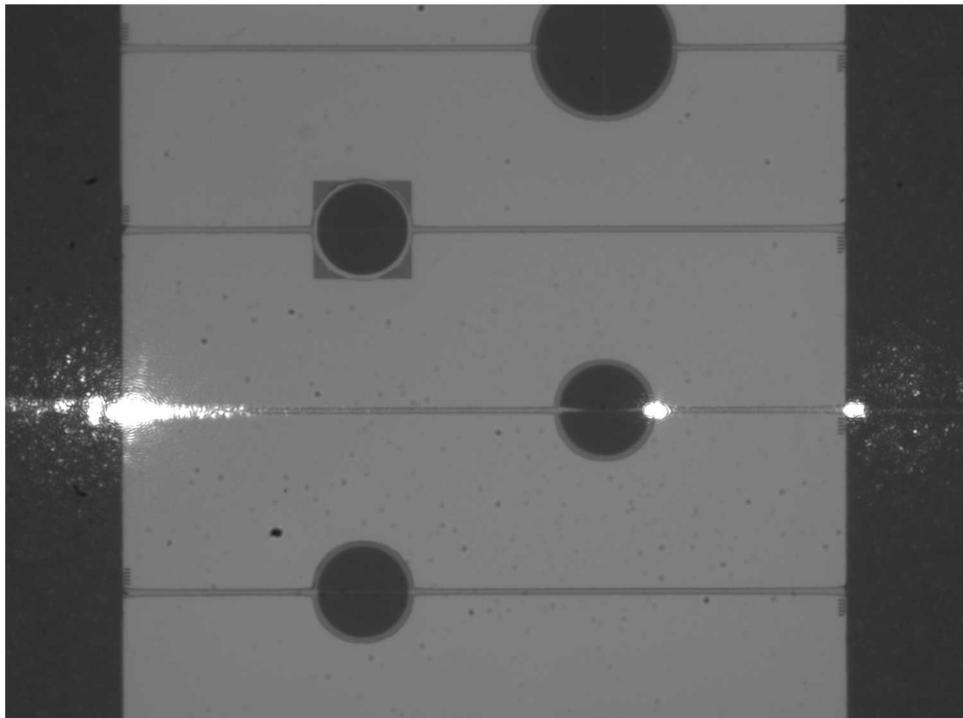
Cs atoms cooled into the trap

Major problem is heat dissipation on deep traps

Propagation loss:

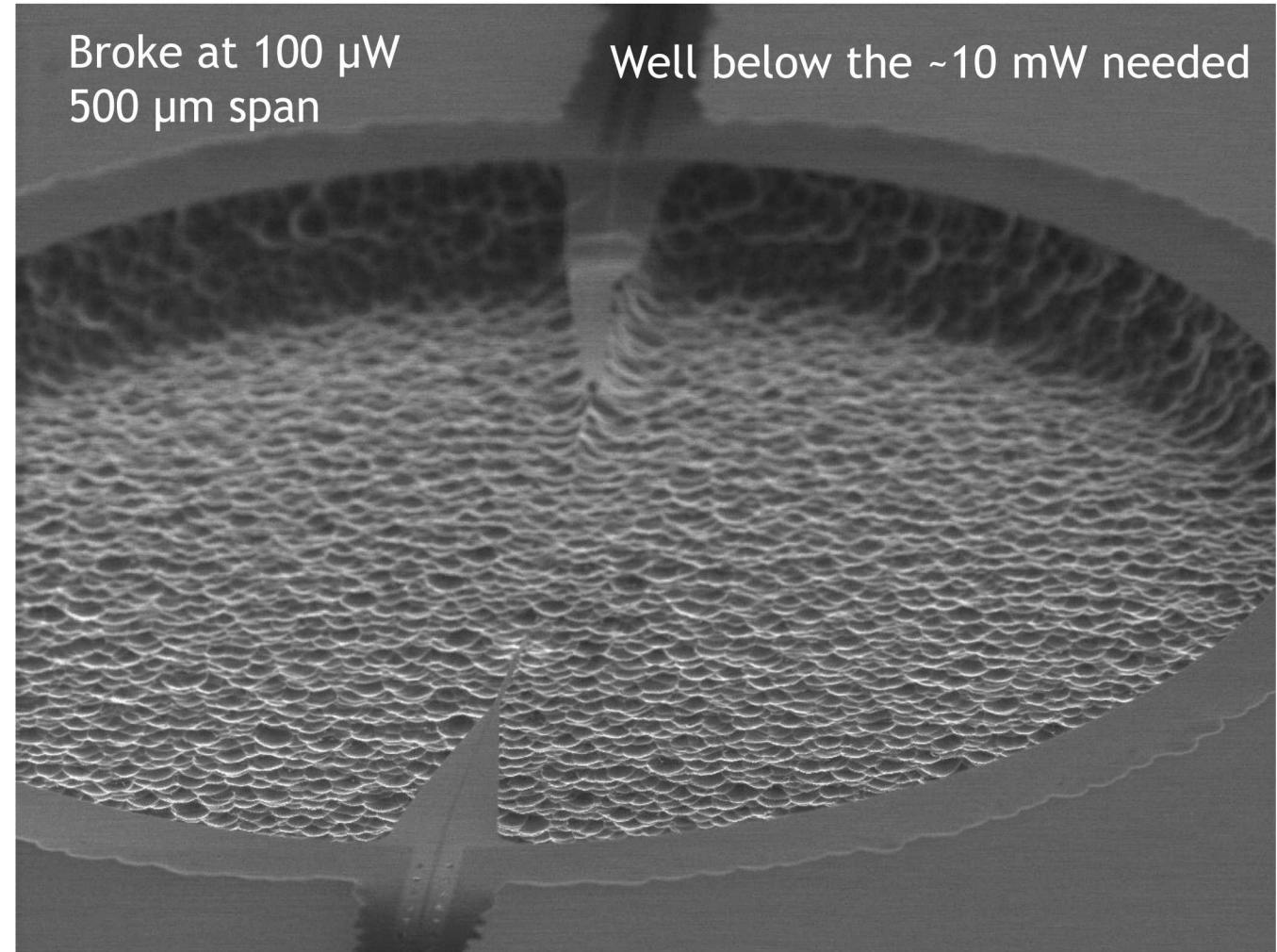
1.0 to 4.5 dB/cm at $\lambda = 935\text{nm}$

Expected 0.1 dB/cm from previous
alumina quality



Broke at 100 μW
500 μm span

Well below the ~10 mW needed



SANDIA

SEI

10.0kV

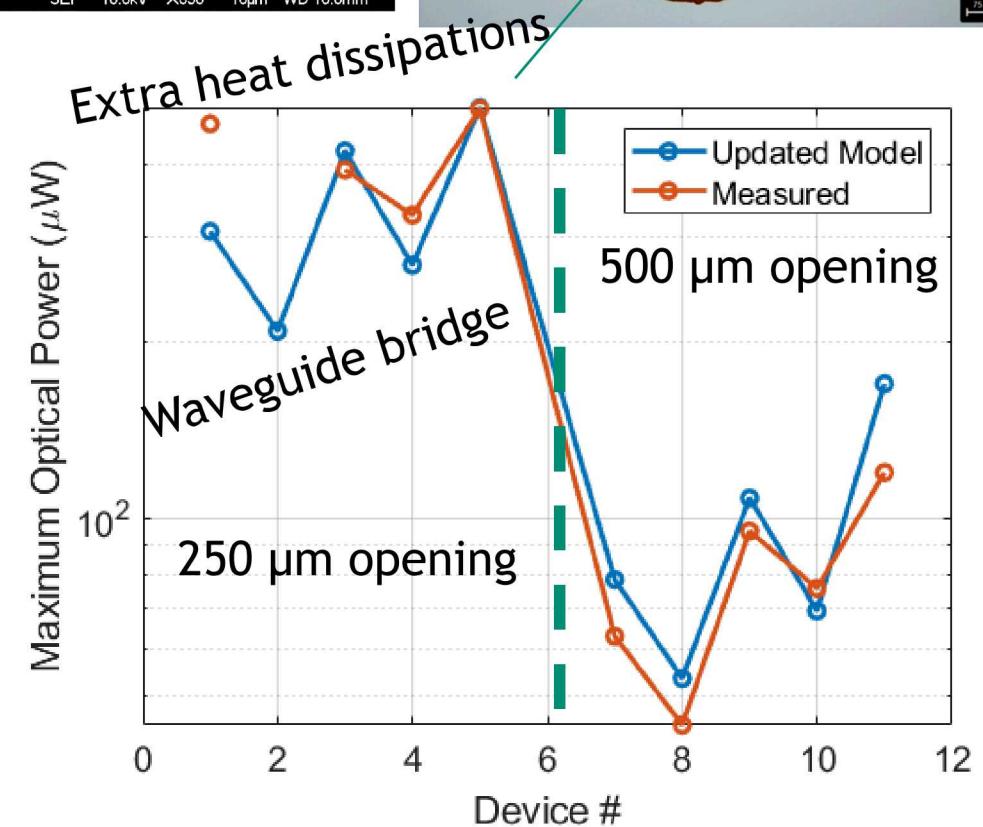
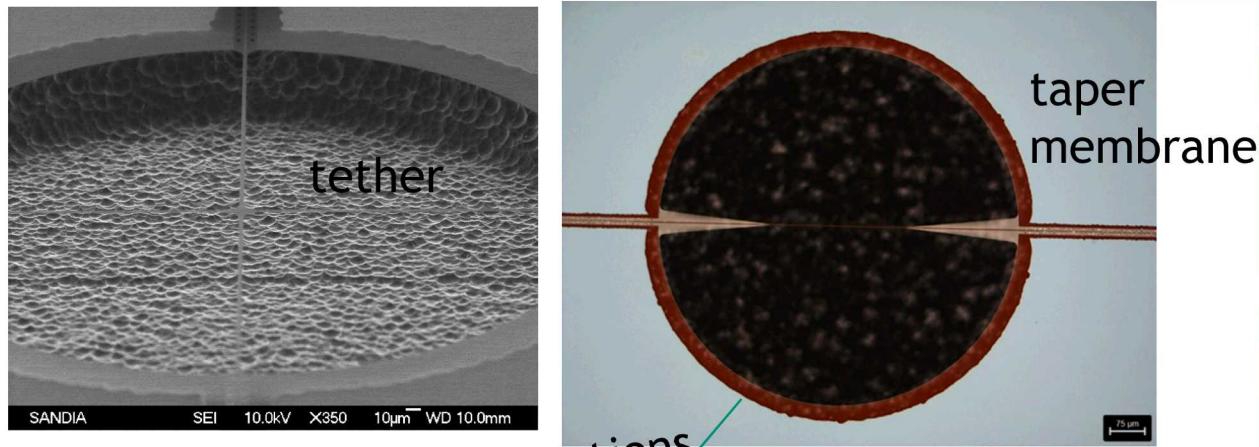
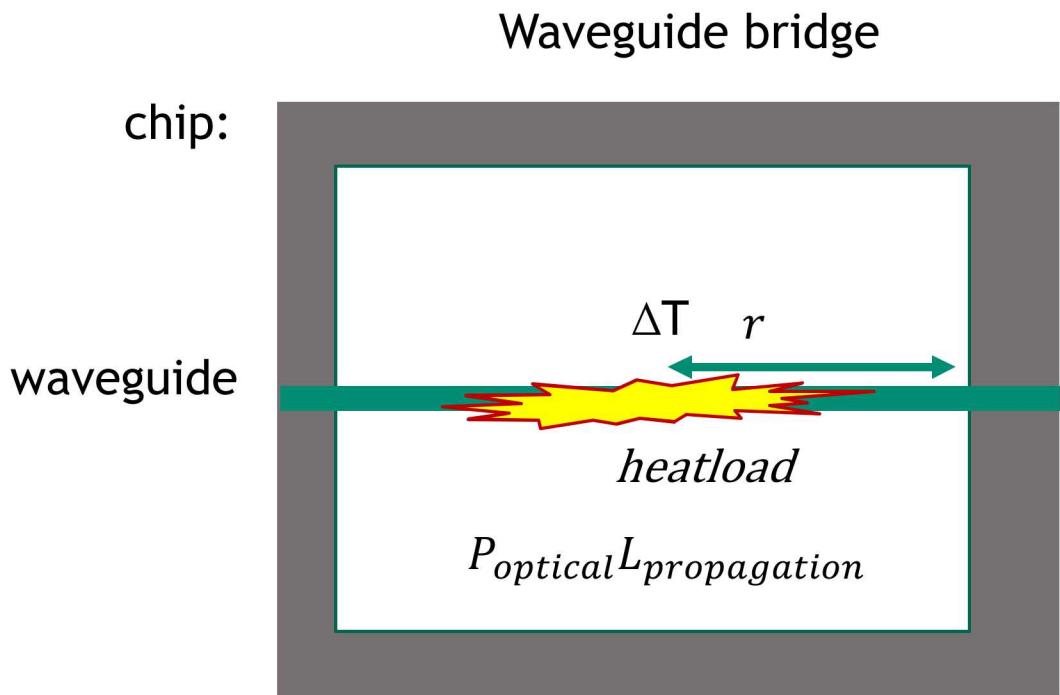
X300

10 μm WD 16.0mm

The waveguides are poor heat sinks

$$\Delta T = \frac{P_{optical} L_{propagation}}{k} \frac{r^2}{A}$$

~ (100s μm) 2
~ 0.1 (μm) 2

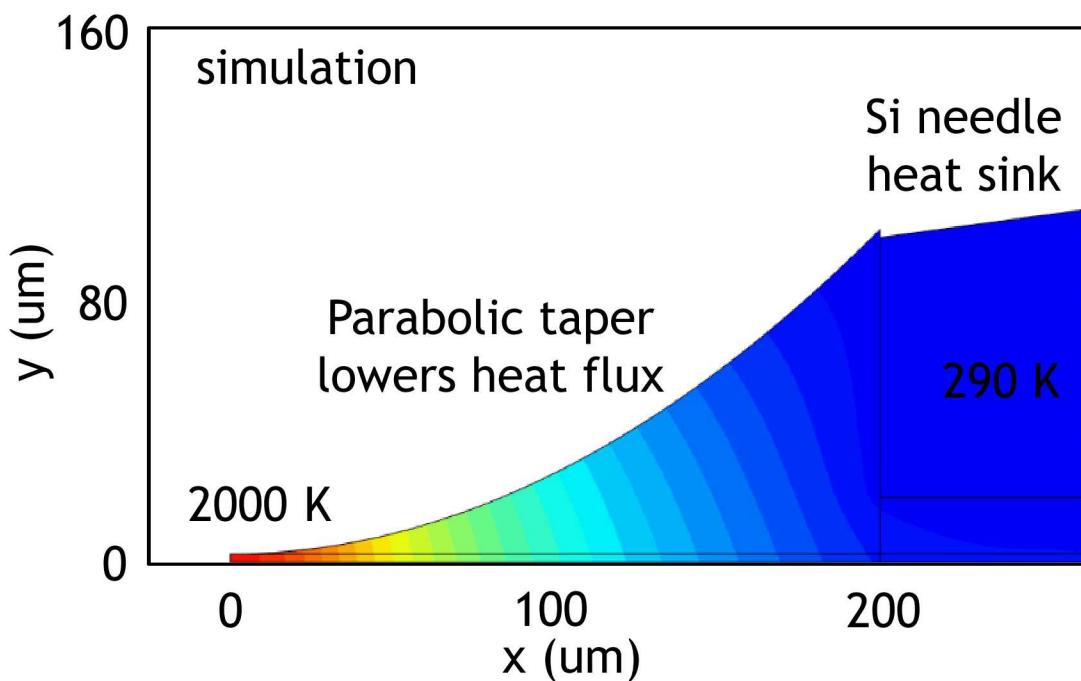
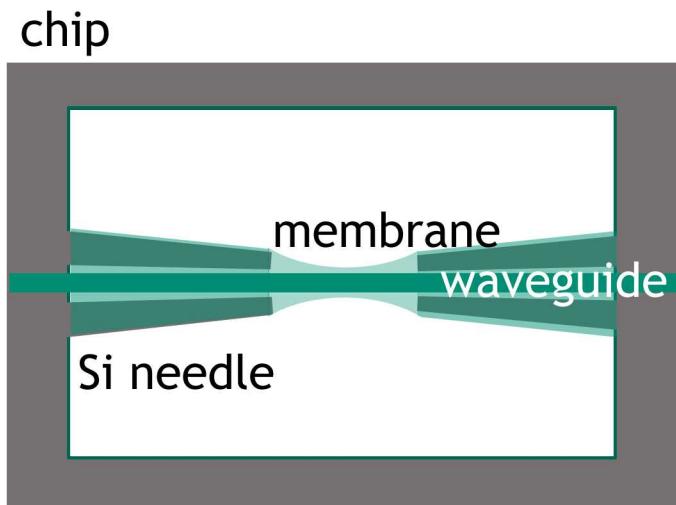


Engineered structures to heat sink

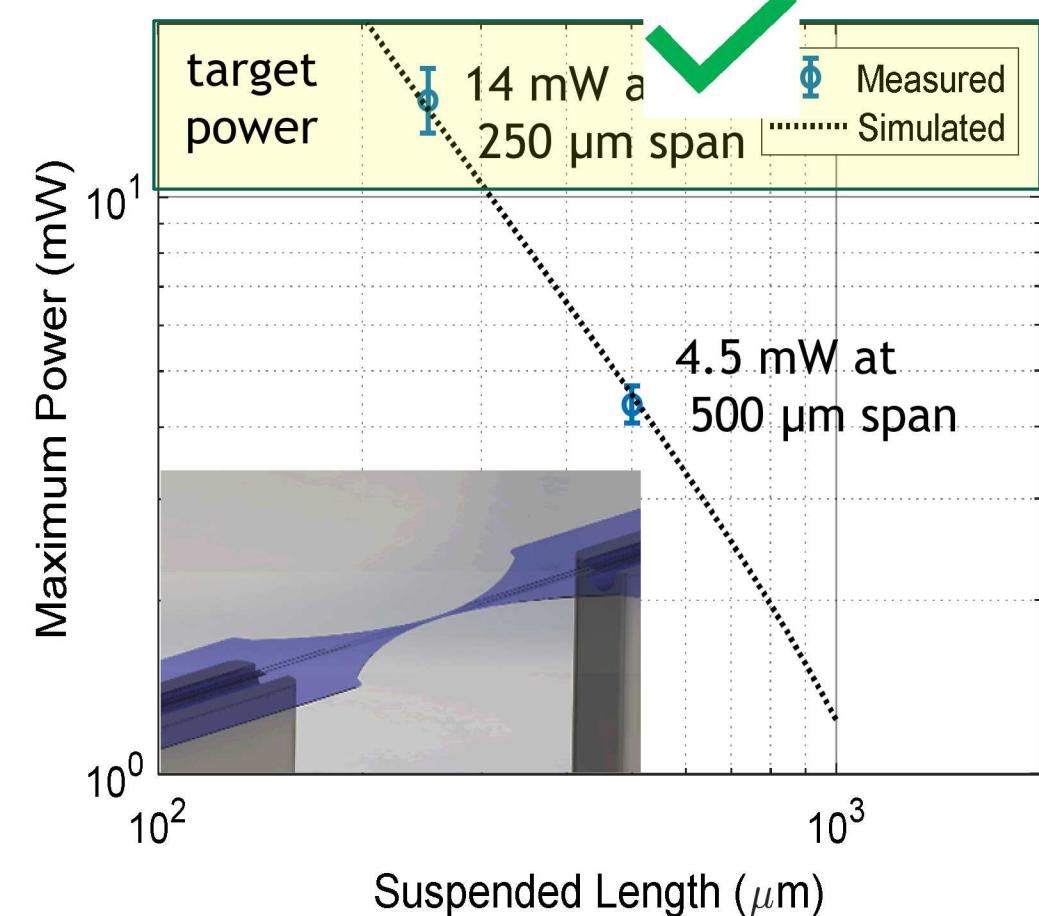
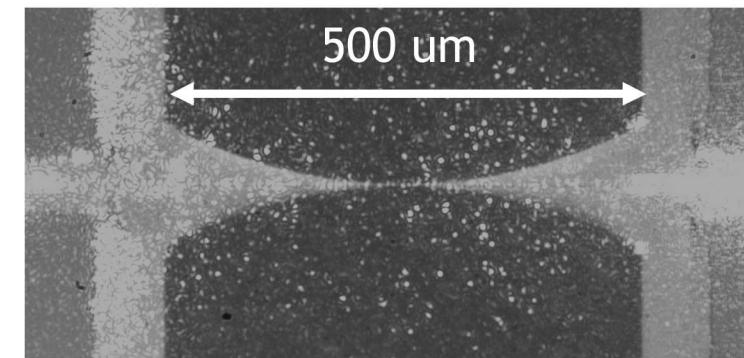


Add

- Si needle
- Parabolic membrane tapper



test structure



Back of the envelop calculation: Estimating number of trapped atoms at a given power

$$\frac{dN}{dt} = R_0 \exp(\gamma_{MOT} t) - \Gamma N - \beta N^2 = 0$$

$$N_{max} = R/\Gamma = C V_{loading} (U_{barrier} - k_B T_{MOT})$$

calculate from nanofiber

Loading volume

$$R \propto \int_{V(U_{trap} < T_{MOT})} dV \rho_{MOT}$$

Barrier height

$$\frac{1}{\Gamma} = \frac{U_{trap} - k_B T_{MOT}}{\frac{dQ}{dt}}$$

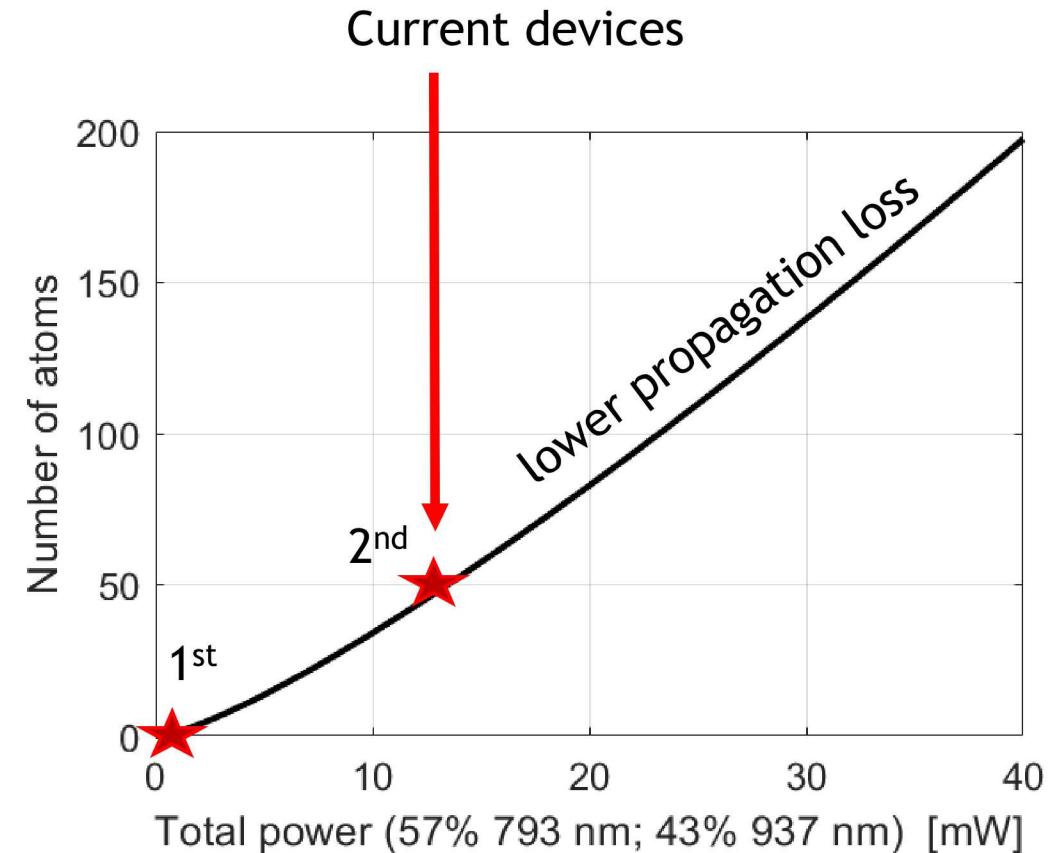
Assumes:

steady state loading

low density of atoms trapped

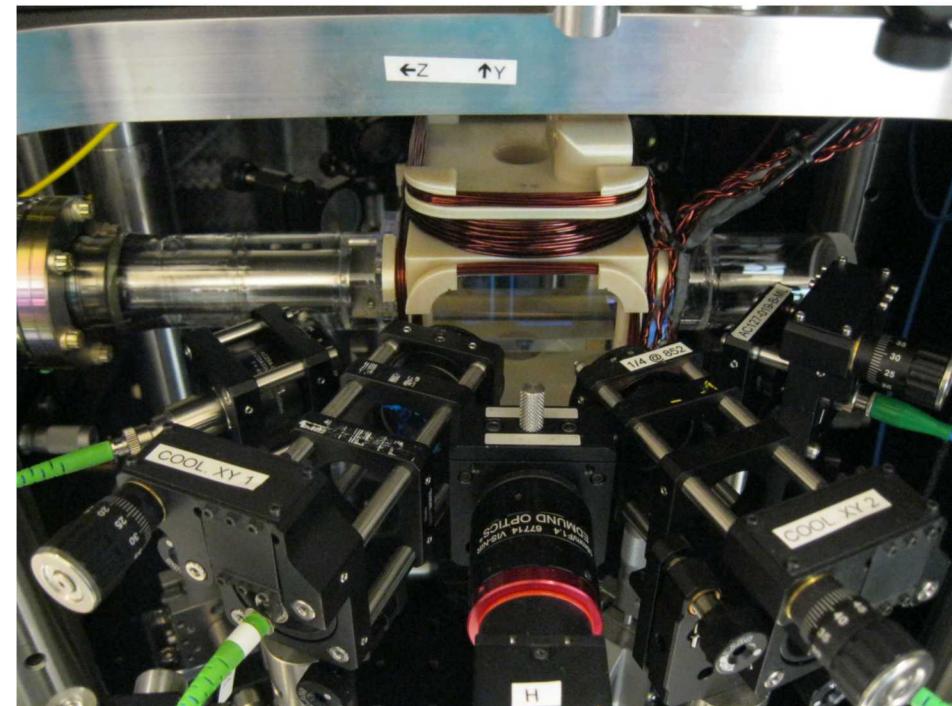
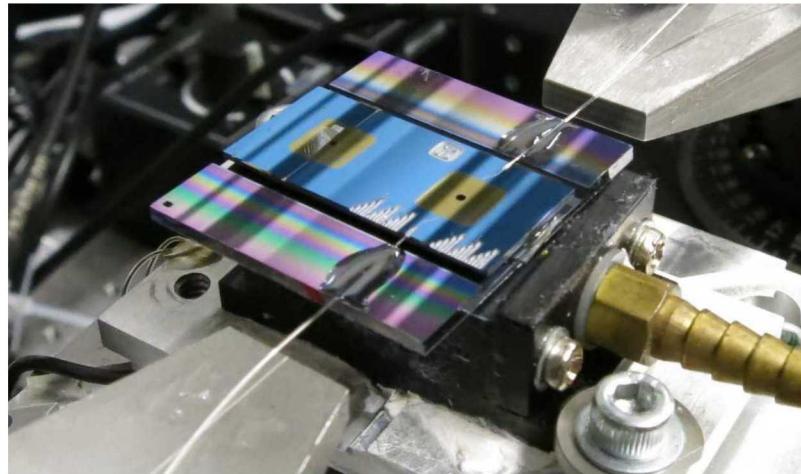
decay set by fixed heating rate (big assumption)

same MOT and MOT-waveguide overlap as nanofiber



Conclusion: we are in a position to trap atoms and perform guided AI on a photonic chip

- Waveguide fabricated for two color atoms trap
- Waveguide exceed power handling needed for trapping
- Chips designed to accommodate MOT formation on trap
- Ready to fabricate for testing with MOT



Acknowledgements

AMO Team



William Kindel¹



Adrian Orozco^{1,2}



Jongmin Lee¹



Grant Biedermann³



Yuan-Yu Jau¹

Fabrication Team



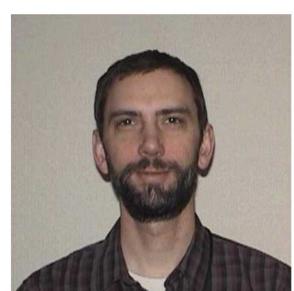
Katherine Musick¹



Nicholas Karl¹



Michael Gehl¹



Andrew Leenheer¹



Andrew Starbuck¹



1. Sandia National Laboratories

2. Center for Quantum Information and Control, University of New Mexico

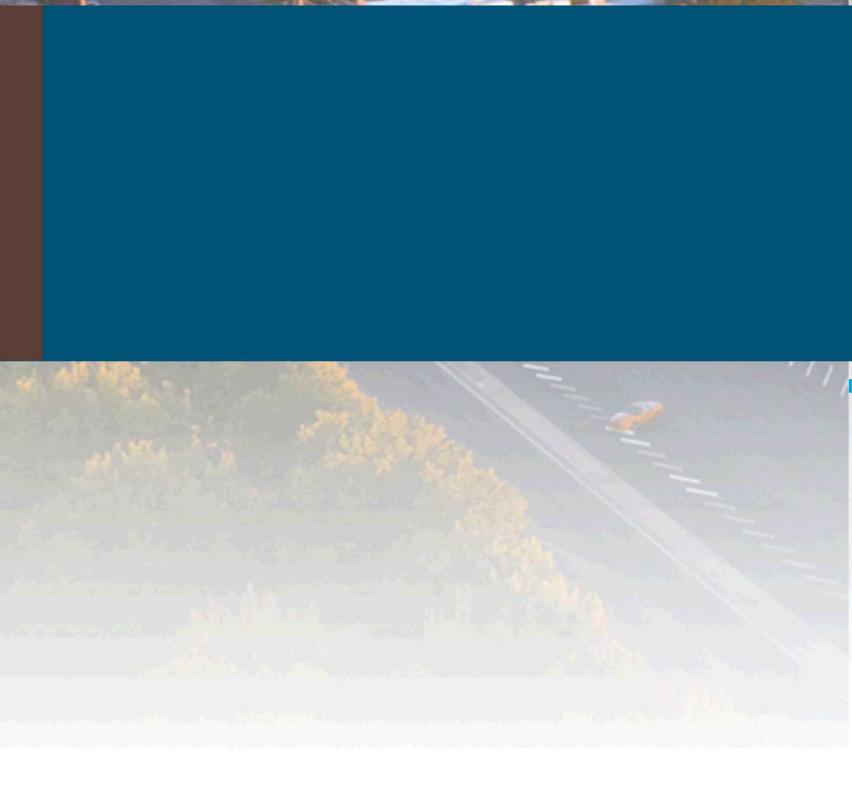
3. Center for Quantum Research and Technology, University of Oklahoma



THANK YOU

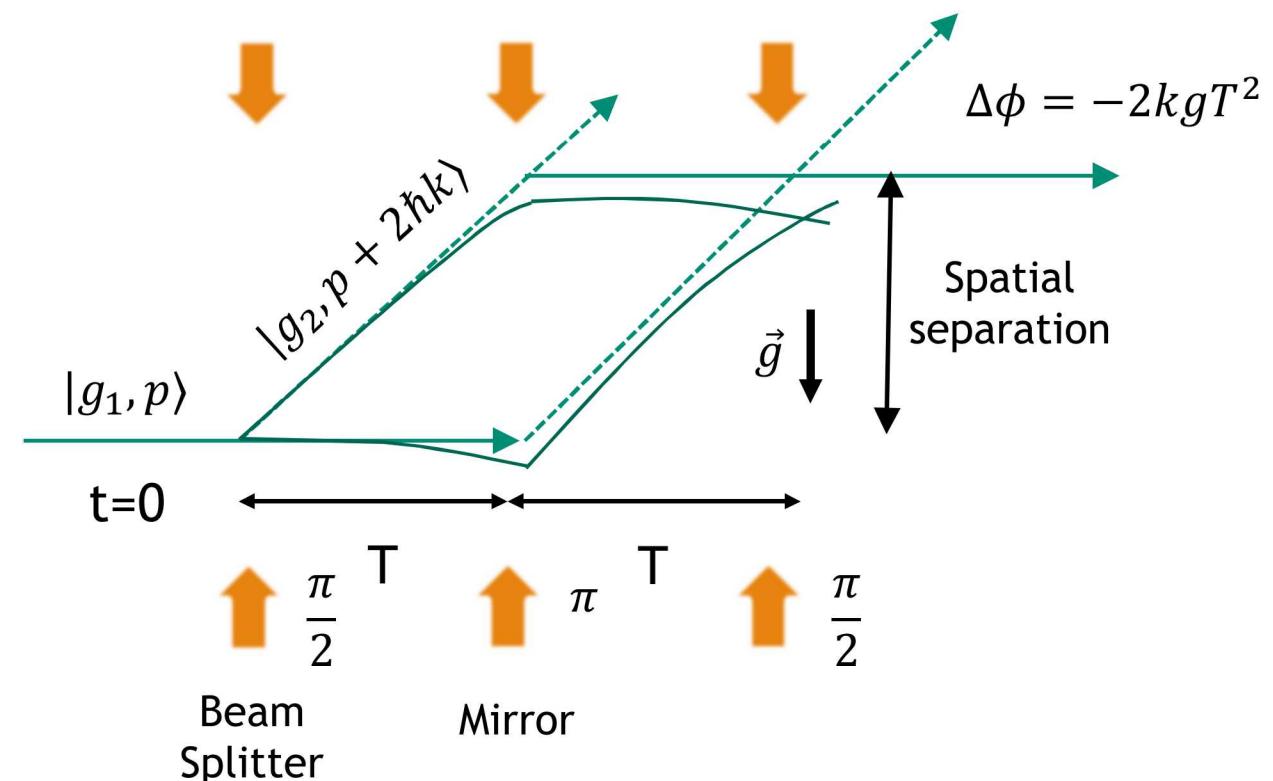
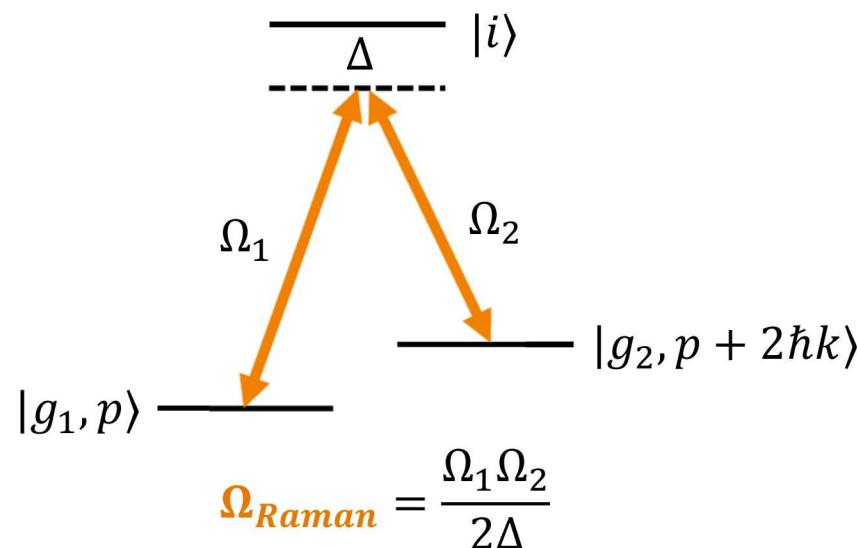


Appendix



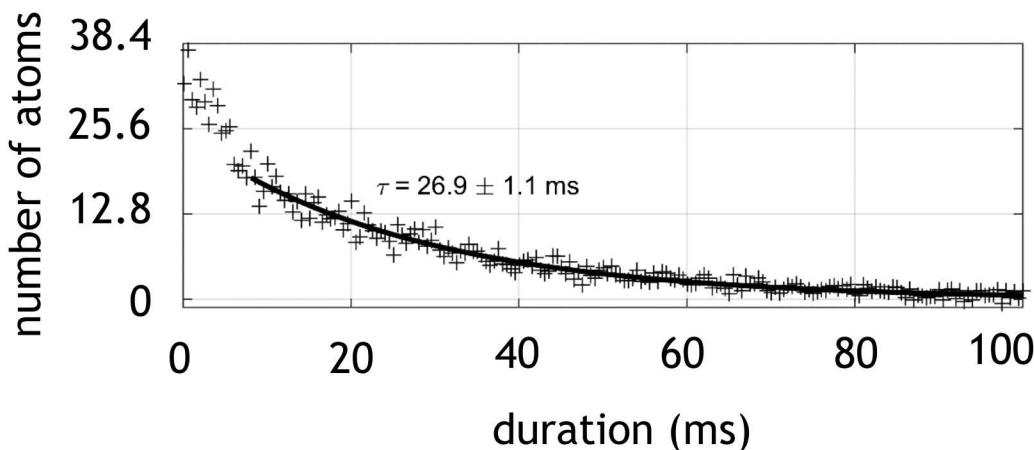
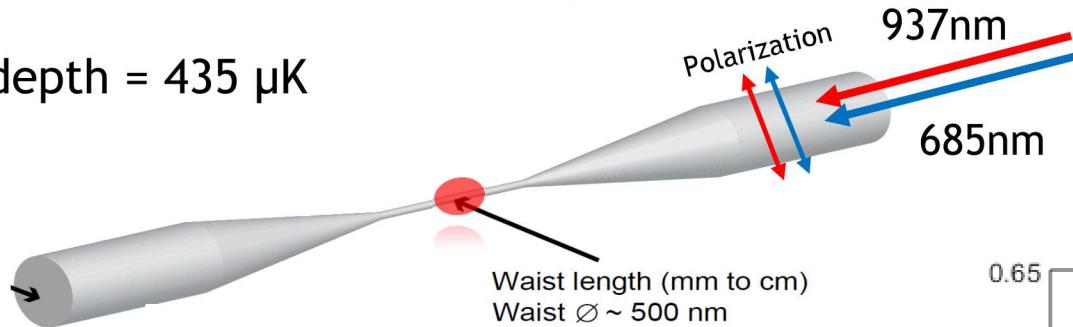
Mach-Zehnder Atom Interferometer sense acceleration

- Doppler sensitive Raman transitions impart a momentum of $\sim 2\hbar k$ onto atom
- Three pulse sequence splits, redirects, and recombines atomic wavepackets
- Laser phase is imprinted onto the wavepacket resulting in precise measurement of spatial phase shift between arms
- Sensitivity can be increased by
 - Longer interrogation time T
 - Large momentum kick



Nano fiber trapping guides our development

Trap depth = 435 μK



Doppler-free Raman beam

